TIP31A/31C
TIP32A/32B/32C

COMPLEMENTARY SILICON POWER TRANSISTORS

APPLICATION

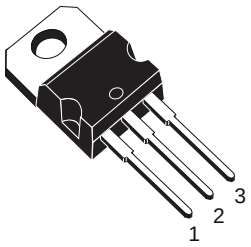
- LINEAR AND SWITCHING INDUSTRIAL EQUIPMENT

DESCRIPTION

The TIP31A and TIP31C are silicon Epitaxial-Base NPN transistors mounted in Jedec TO-220 plastic package. They are intented for use in medium power linear and switching applications.

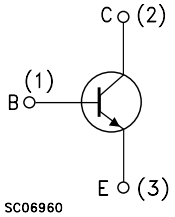
The complementary PNP types are TIP32A and TIP32C respectively.

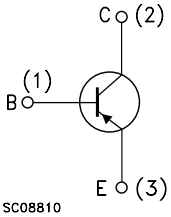
Also TIP32B is a PNP type.



TO-220

INTERNAL SCHEMATIC DIAGRAM





ABSOLUTE MAXIMUM RATINGS

Symbol	Parameter		Value			Unit
		NPN	TIP31A		TIP31C	
		PNP	TIP32A	TIP32B	TIP32C	
V_{CBO}	Collector-Base Voltage (I_E = 0)		60	80	100	V
V_{CEO}	Collector-Emitter Voltage (I_B = 0)		60	80	100	V
V_{EBO}	Emitter-Base Voltage (I_C = 0)		5			V
I_C	Collector Current		3			A
I_{CM}	Collector Peak Current		5			A
I_B	Base Current		1			A
P_{tot}	Total Dissipation at $T_{case} \leq 25\ ^oC$ $T_{amb} \leq 25\ ^oC$		40 2			W W
T_{stg}	Storage Temperature		-65 to 150			^oC
T_j	Max. Operating Junction Temperature		150			^oC

For PNP types voltage and current values are negative

THERMAL DATA

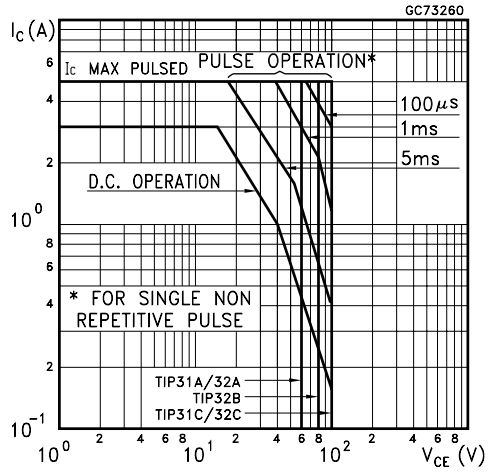
$R_{thj\text{-}case}$	Thermal Resistance Junction-case	Max	3.12	$^oC/W$
$R_{thj\text{-}amb}$	Thermal Resistance Junction-ambient	Max	62.5	$^oC/W$

ELECTRICAL CHARACTERISTICS (T_{case} = 25 ^oC unless otherwise specified)

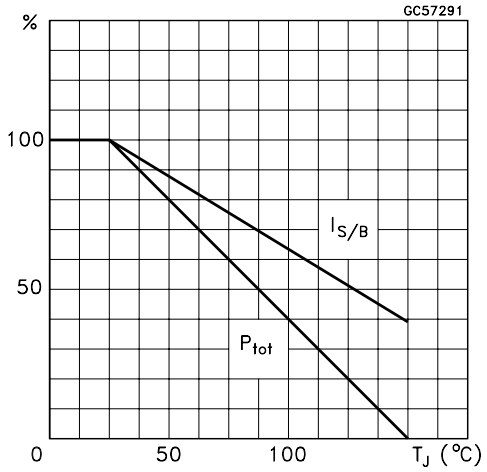
Symbol	Parameter	Test Conditions	Min.	Typ.	Max.	Unit
I_{CEO}	Collector Cut-off Current (I_B = 0)	for **TIP31A/32A** V_{CE} = 30 V for **TIP31C/32B/32C** V_{CE} = 60 V			0.3 0.3	mA mA
I_{CES}	Collector Cut-off Current (V_{BE} = 0)	for **TIP31A/32A** V_{CE} = 60 V for **TIP/32B** V_{CE} = 80 V for **TIP31C/32C** V_{CE} = 100 V			0.2 0.2 0.2	mA mA mA
I_{EBO}	Emitter Cut-off Current (I_C = 0)	V_{EB} = 5 V			1	mA
$V_{CEO(sus)}$*	Collector-Emitter Sustaining Voltage (I_B = 0)	I_C = 30 mA **for TIP31A/32A** **for TIP32B** **for TIP31C/32C**	 60 80 100			 V V V
$V_{CE(sat)}$*	Collector-Emitter Saturation Voltage	I_C = 3 A I_B = 375 mA			1.2	V
$V_{BE(on)}$*	Base-Emitter Voltage	I_C = 3 A V_{CE} = 4 V			1.8	V
h_{FE}*	DC Current Gain	I_C = 1 A V_{CE} = 4 V I_C = 3 A V_{CE} = 4 V	25 10		 50	
h_{fe}	Small Signall Current Gain	I_C = 0.5 A V_{CE} = 10 V f = 1 KHz I_C = 0.5 A V_{CE} = 10 V f = 1 MHz	20 3			

* Pulsed : pulse duration = 300 µs, duty cycle ≤ 2%
For PNP types voltage and current values are negative.

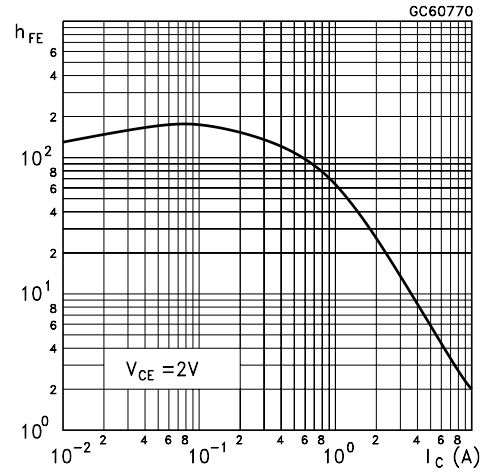
Safe Operating Area



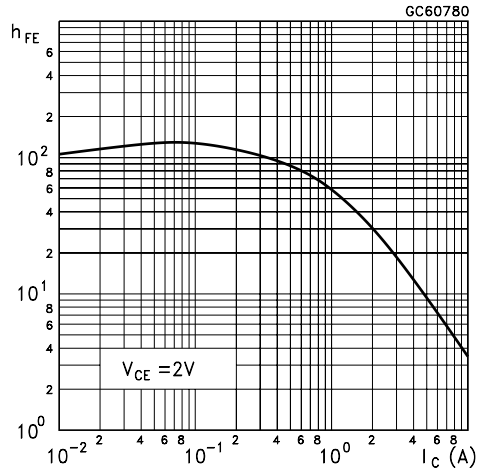
Derating Curves



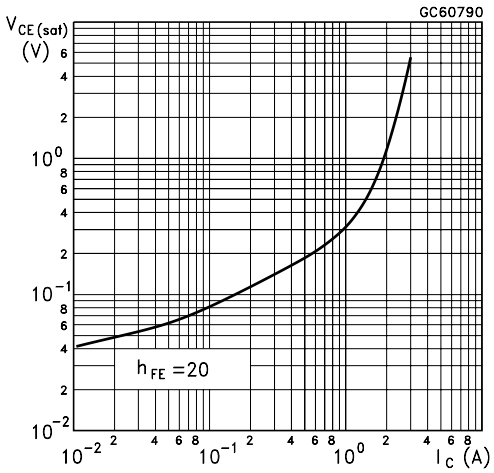
DC Current Gain (NPN type)



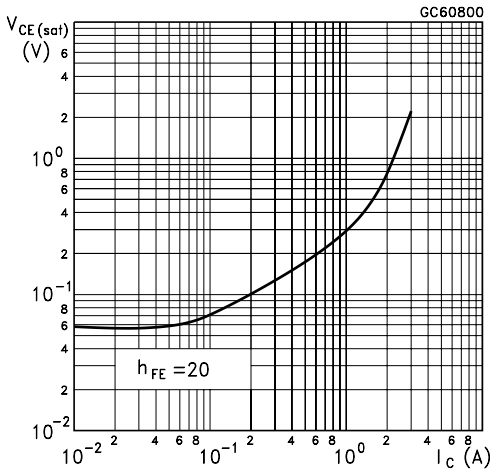
DC Current Gain (PNP type)



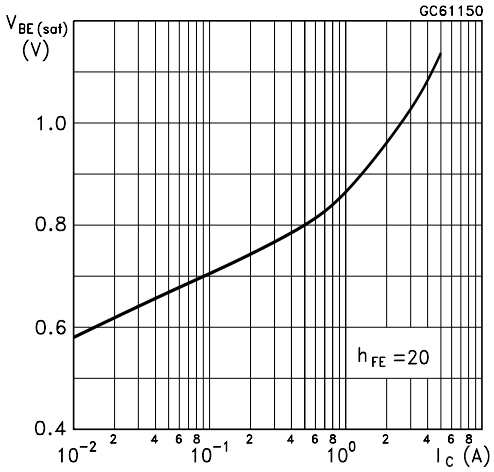
Collector-Emitter Saturation Voltage (NPN type)



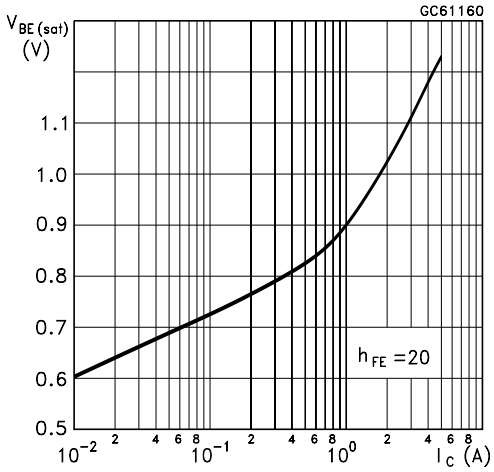
Collector-Emitter Saturation Voltage (PNP type)



Base-Emitter Saturation Voltage (NPN type)

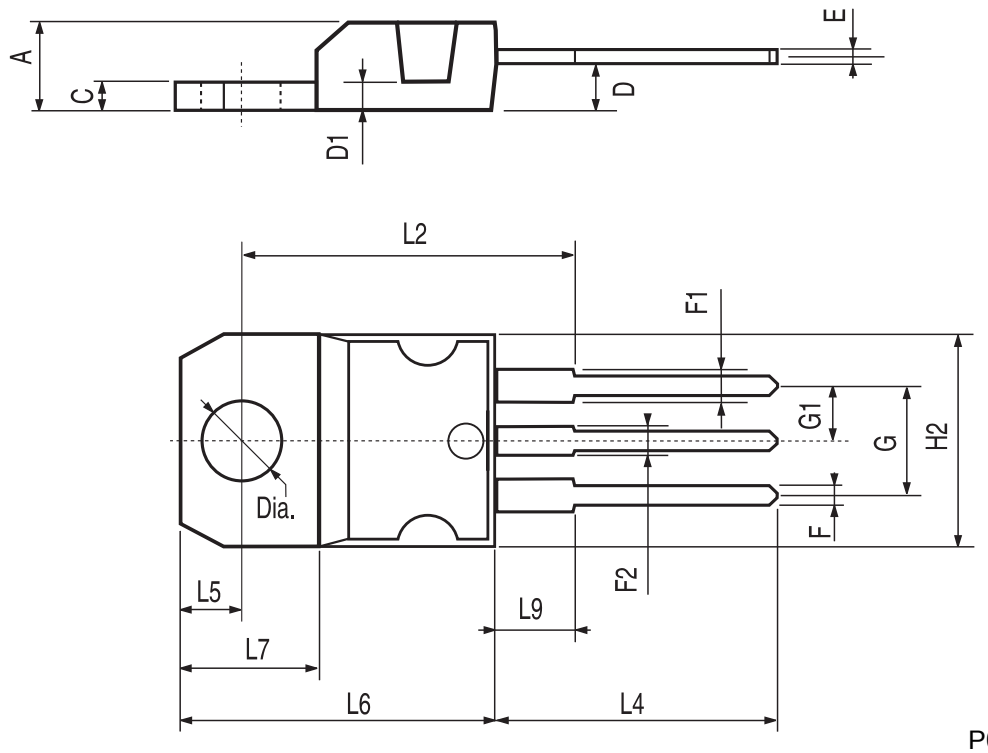


Collector-Base Capacitance (PNP type)



TO-220 MECHANICAL DATA

DIM.	mm			inch		
	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.
A	4.40		4.60	0.173		0.181
C	1.23		1.32	0.048		0.051
D	2.40		2.72	0.094		0.107
D1		1.27			0.050	
E	0.49		0.70	0.019		0.027
F	0.61		0.88	0.024		0.034
F1	1.14		1.70	0.044		0.067
F2	1.14		1.70	0.044		0.067
G	4.95		5.15	0.194		0.203
G1	2.4		2.7	0.094		0.106
H2	10.0		10.40	0.393		0.409
L2		16.4			0.645	
L4	13.0		14.0	0.511		0.551
L5	2.65		2.95	0.104		0.116
L6	15.25		15.75	0.600		0.620
L7	6.2		6.6	0.244		0.260
L9	3.5		3.93	0.137		0.154
DIA.	3.75		3.85	0.147		0.151



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